

Evaluation of the effect of sulfur poisoning on the performance of Ni/CGO based SOFC anodes

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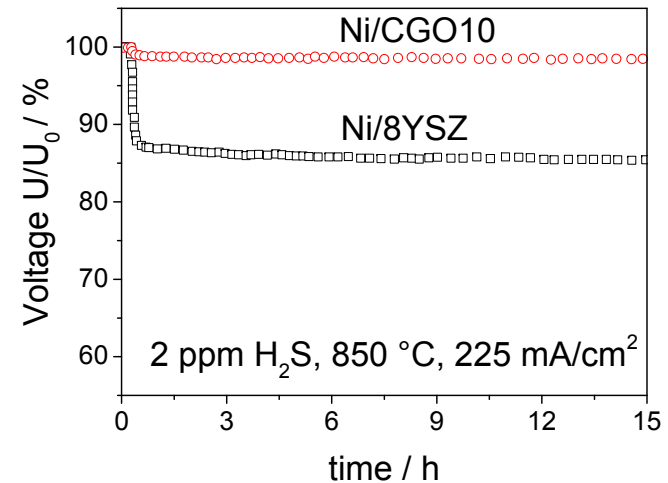
Outline

- Motivation and aim of the work
- Experimental procedure
- Results
 - Short-term sulfur poisoning
 - Long-term sulfur poisoning
- Summary and conclusions



Motivation and aim of the work

- Sulfur-containing impurities in natural gas and biogas
- Higher sulfur tolerance of Ni/CGO than Ni/YSZ
- CGO: MIEC + catalytically active for H₂ oxidation [2 – 4]
- Mechanism is not fully understood



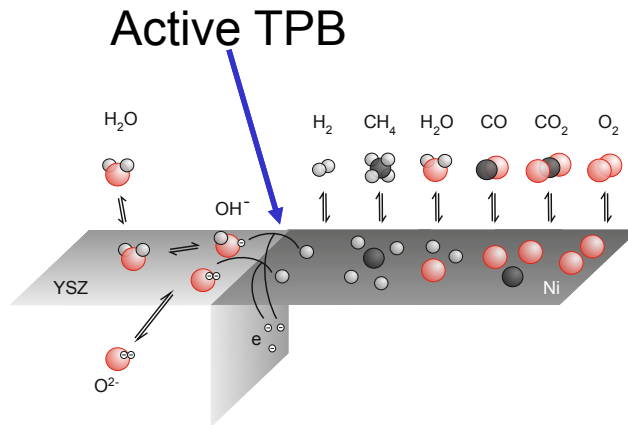
Goal: Elucidation of sulfur poisoning and underlying hydrogen oxidation mechanism on Ni/CGO-based anodes

[1] Kavarucu et al., *Journal of Power Sources*, 217, (2012), 364; [2] Primdahl, Mogensen, *Solid State Ionics*, 152, (2002), 597; [3] Nakamura, *J. Electrochem. Soc.*, 155, (2008), B563; [4] Chueh et al., *Nat. Mater.*, 11, (2011), 155

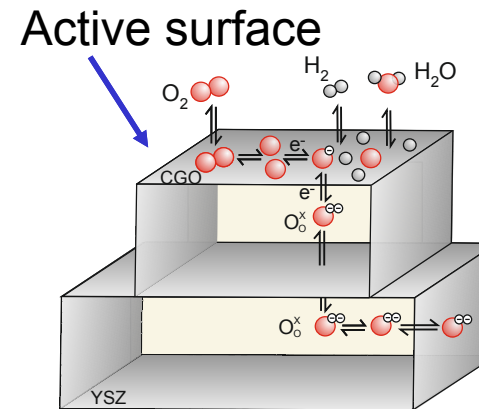


Motivation and aim of the work

Ni/YSZ based anodes



Ni/CGO based anodes

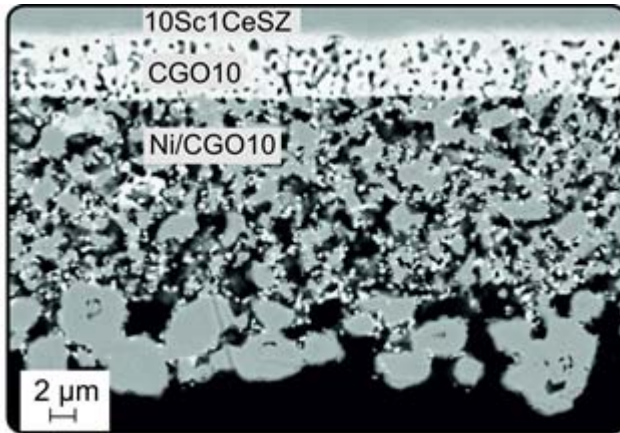


- Is Ni pure electronic conductor? [1 – 3]
- Sulfur poisoning of pure CGO electrode possible [4]
- Sulfur poisoning of CGO or Ni?

[1] Chueh et al., *Nat. Mater.*, 11, (2011), 155; [2] Feng et al., *Nat. Commun.*, 5, (2014), 1; [3] Chueh et al., *Solid State Ionics*, 179, (2008), 1036. [4] Mirfakhraei et al., *J. Power Sources*, 243, (2013), 95;

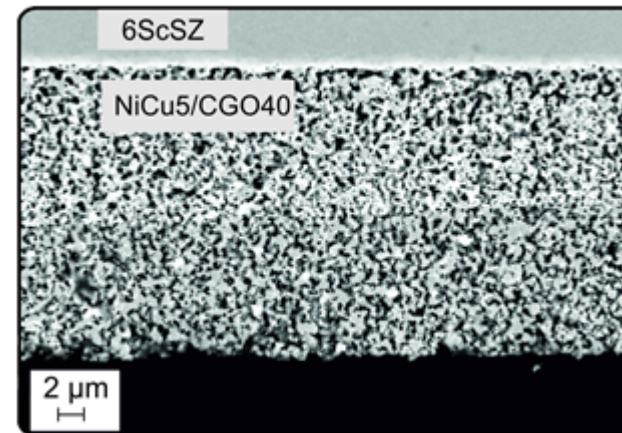


Experimental Procedure



Ni/CGO10 anode (25 μm)

- 160 μm 10Sc1CeSZ electrolyte
- 65 μm LSM/ScSZ cathode



NiCu5/CGO40 anode (25 μm, HEXIS)

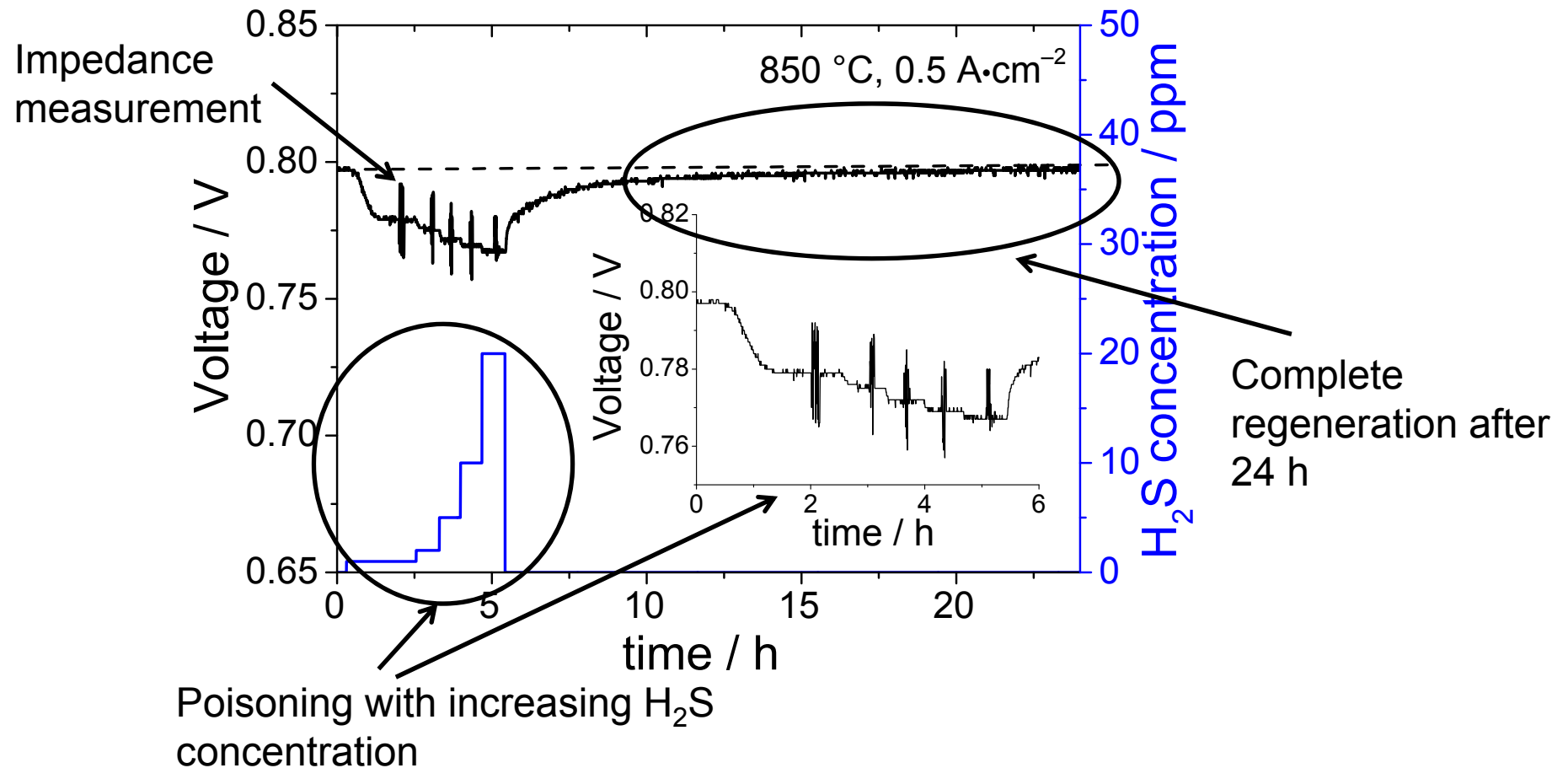
- 160 μm 6ScSZ electrolyte
- 70 μm LSM/ScSZ cathode

- Systematic parameter study of short-term poisoning at different current density and temperatures
- Long-term experiments
- In-situ monitoring with electrochemical impedance spectroscopy

Experimental Procedure: Testing protocol short-term poisoning

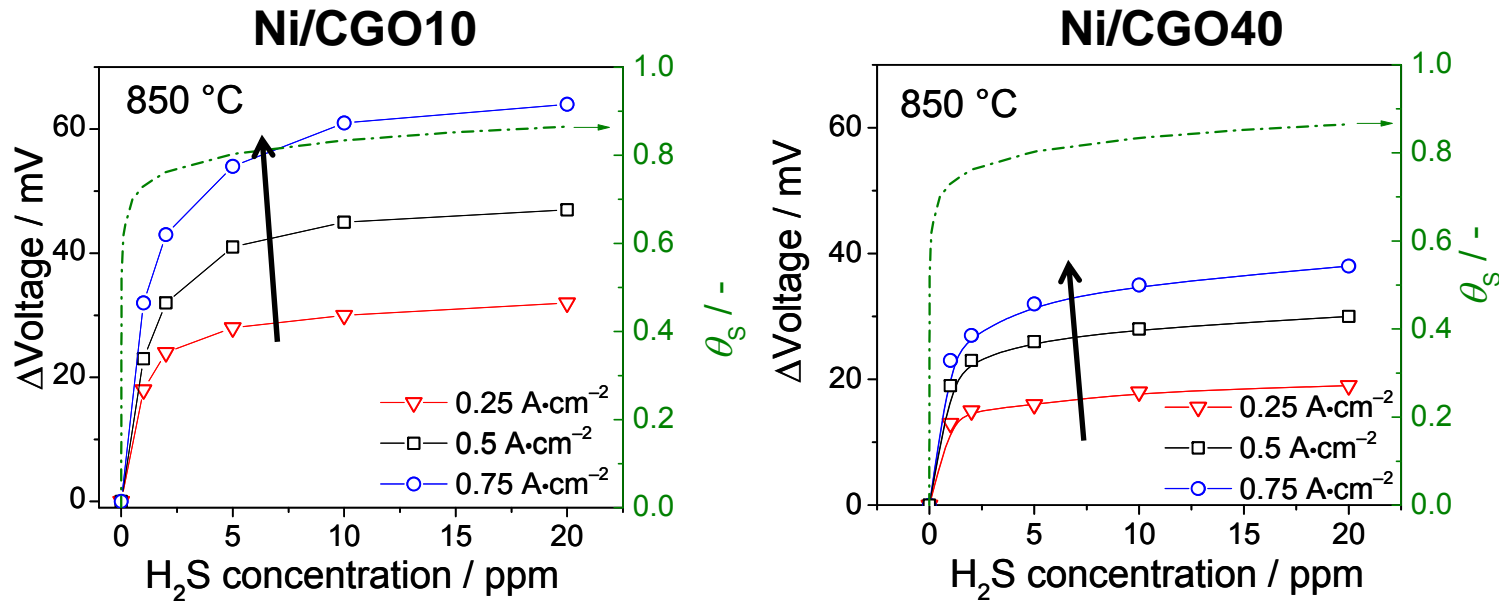
$T = 850^{\circ}\text{C}$, $i = 0.5 \text{ A}\cdot\text{cm}^{-2}$

Anode gas: 97 % H_2 , 3 % H_2O + 1 – 20 ppm H_2S



Short-term sulfur poisoning: Effect of current density on performance

$i = 0.25 - 0.75 \text{ A}\cdot\text{cm}^{-2}$, $T = 850^\circ\text{C}$, 97 % H_2 , 3 % H_2O + 1 – 20 ppm H_2S



- Saturation effect similar to sulfur coverage on Ni

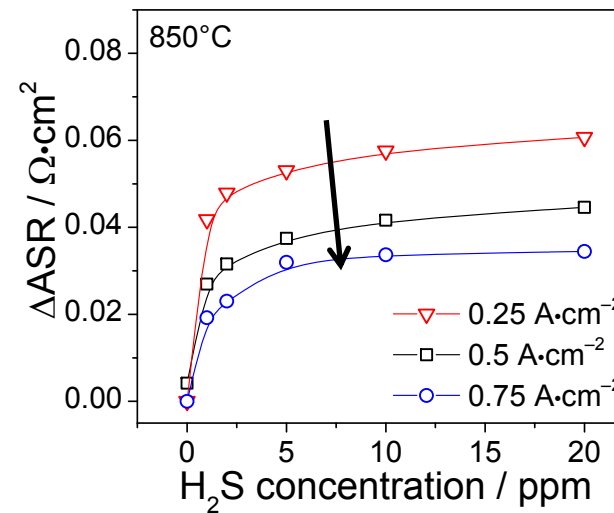
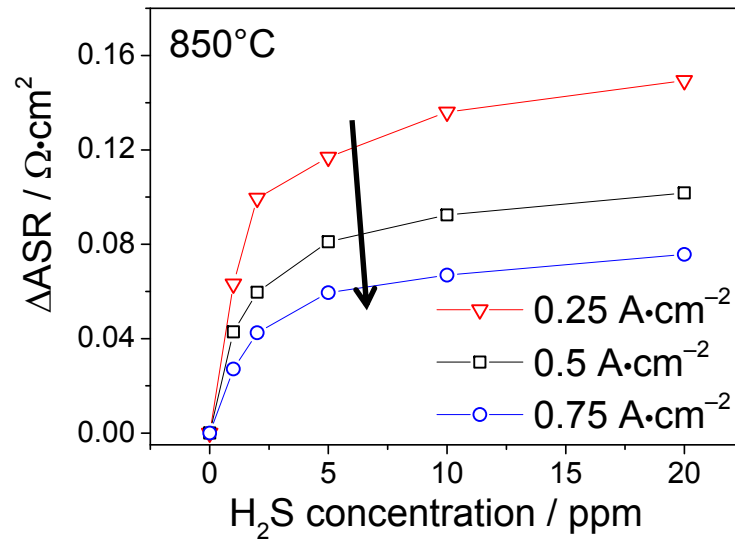
- Temkin isotherm: $\frac{p_{\text{H}_2\text{S}}}{p_{\text{H}_2}} = \exp(\Delta h_0^0(1 - a\theta_s) / RT - \Delta s^0 / R)$

⇒ Sulfur poisoning of Ni surface?



Short-term sulfur poisoning: Effect of current density on ASR

$i = 0.25 - 0.75 \text{ A}\cdot\text{cm}^{-2}$, $T = 850^\circ\text{C}$, 97 % H_2 , 3 % H_2O + 1 – 20 ppm H_2S

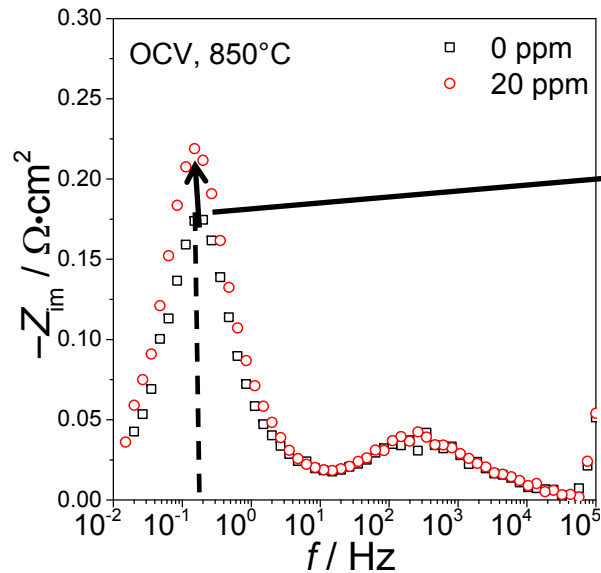


- Mitigation effect at high current densities
- Reason: increasing water content?
- Conclusions about sulfur poisoning mechanism remain difficult



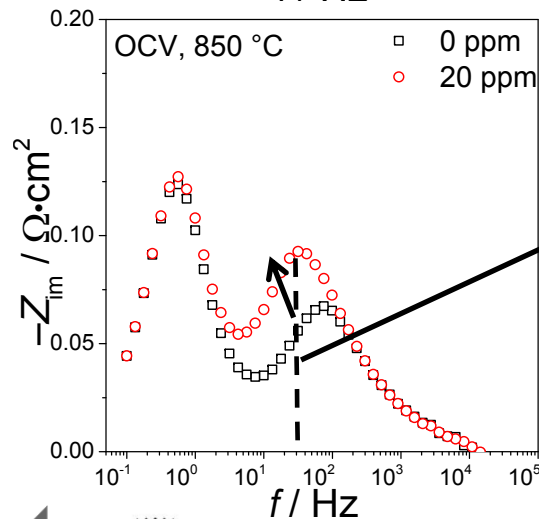
Ni/CGO10 vs. Ni/CGO40: Impedance analysis

$T = 850^{\circ}\text{C}$, OCV, 97 % H_2 , 3 % H_2O + 1 – 20 ppm H_2S



Ni/CGO10-based cell:

- Sulfur influence at ~ 0.2 Hz
- TPB charge transfer process of Ni/YSZ: $\sim 10^3$ Hz
- Characteristic frequency of surface charge transfer process of pure CGO10



Ni/CGO40-based cell:

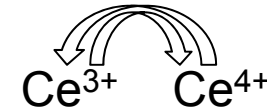
- Influence of sulfur on anode surface process at ~ 50 Hz
- No influence on LF process

⇒ Change of peak frequency of sulfur-affected process by 2 orders of magnitude



Discussion: Ni/CGO

- Chemical capacitance at CGO surface due to mixed valent Ce ions and charged adsorbates (e.g. OH⁻)
- Rate-limiting step:
$$\text{Ce}^{4+} + \text{OH}_{\text{CGO}}^- \rightarrow \text{Ce}^{3+} + \text{OH}_{\text{CGO}} [1,2]$$
- Gd doping reduces amount of Ce³⁺ through stabilization of Ce⁴⁺
- Reflected by lower electronic conductivity
- Reason for lower capacitance value?

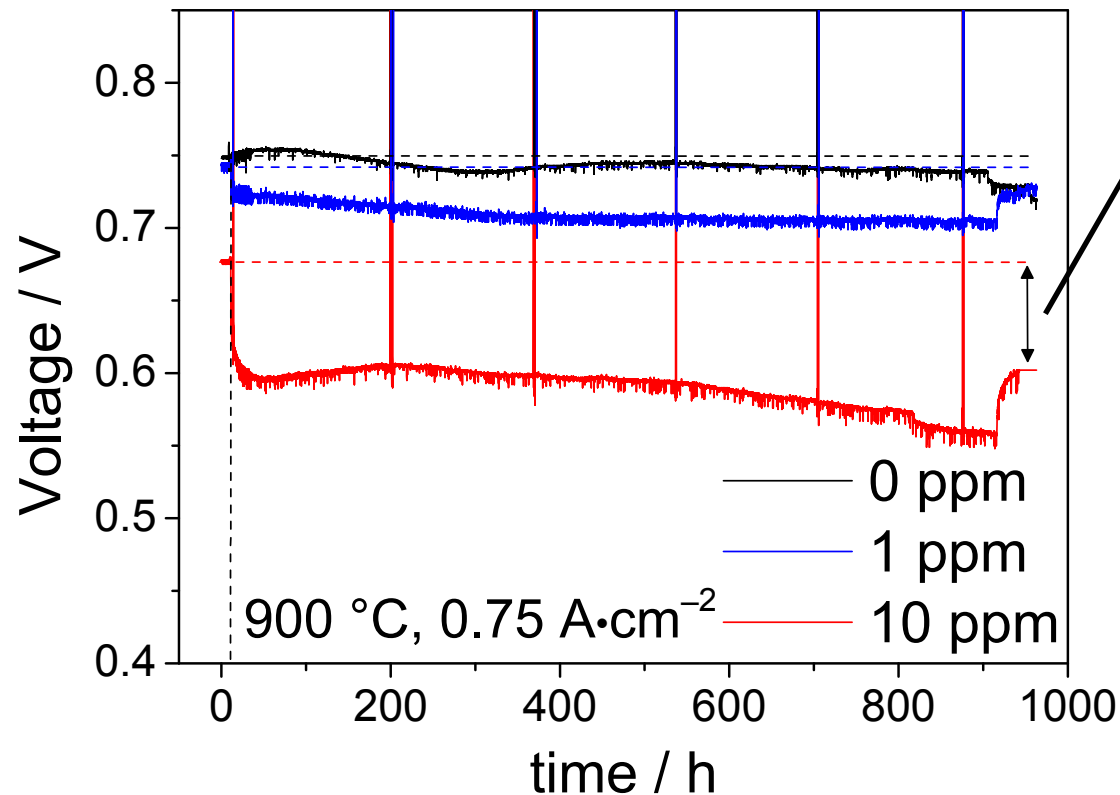


⇒ Peak frequency shift of the same process by 2 orders of magnitude



Long-term sulfur poisoning

$T = 900\text{ }^{\circ}\text{C}$, $0.75\text{ A}\cdot\text{cm}^{-2}$, 97 % H_2 , 3 % H_2O + 0, 1, 10 ppm H_2S
NiCu5/CGO40 anode



- Sulfur-induced irreversible degradation
- 10 ppm > threshold?
- Combination of low potential and sulfur influence?

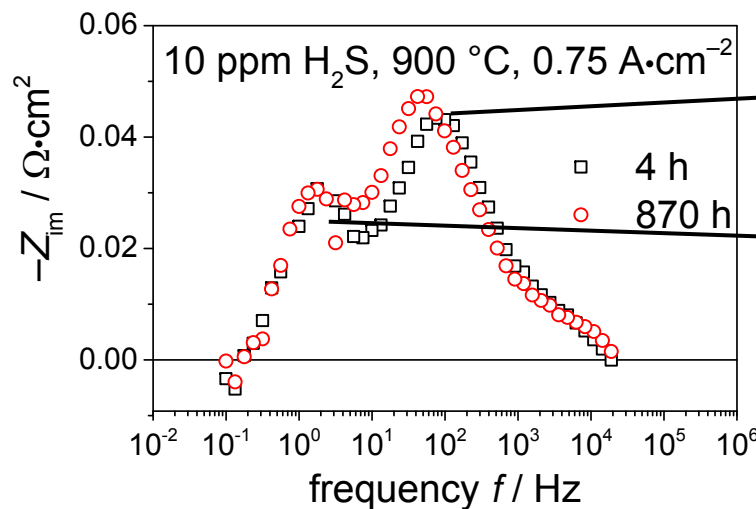
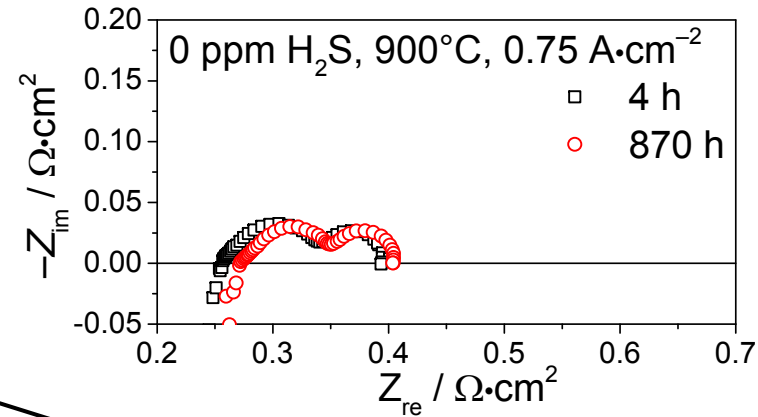
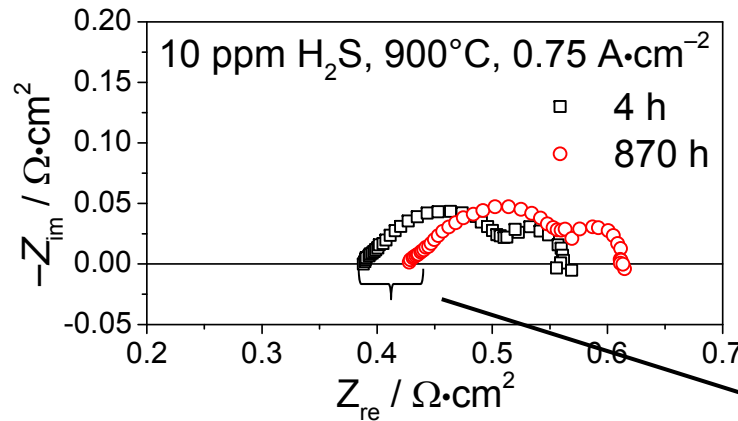
⇒ More experiments needed



Long-term sulfur poisoning: Impedance analysis

$T = 900\text{ }^{\circ}\text{C}$, $0.75\text{ A}\cdot\text{cm}^{-2}$, 97 % H_2 , 3 % H_2O + 0, 1, 10 ppm H_2S

NiCu5/CGO40 anode



- Increasing Ohmic resistance
- Increasing resistance of anode charge transfer process
- No change in LF resistance

⇒ Post mortem analysis necessary for further understanding



Summary and conclusions

- Extensive characterization of sulfur poisoning of Ni/CGO10 and Ni/CGO40-based anodes
- Reversible short-time poisoning
- Ni/CGO10 vs. Ni/CGO40: Capacitance of anode surface process changes by ~ 2 orders of magnitude
- Ni/CGO40: Long-term stability demonstrated for 1 ppm H₂S, irreversible degradation at 10 ppm
- Next step: Sulfur poisoning of reformat-fuelled SOFC
- Investigation of model electrodes required for deeper understanding of the mechanism



Acknowledgments

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Thank you for your attention!



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